

ADuM340E/ADuM341E/ADuM342E

5.7 kV/3.0 kV rms Quad Digital Isolators

FEATURES

- ▶ High common-mode transient immunity: 180 kV/μs typical
- ▶ High robustness to radiated and conducted noise
- ▶ Low propagation delay
 - ▶ 6.2 ns typical (10 ns maximum) for 5 V operation
- ▶ Low dynamic power consumption, <1.65 mA/ch at 1 Mbps
- ▶ 2.25 V to 5.5 V level translation
- ▶ 150 Mbps maximum guaranteed data rate for 5 V operation
- ▶ High temperature operation: 125°C
- ▶ **Safety and regulatory approvals**
 - ▶ DIN EN IEC 60747-17 (VDE 0884-17)
 - ▶ $V_{IORM} = 1173$ V peak, SOIC (RW-16)
 - ▶ $V_{IORM} = 566$ V peak, QSOP (RQ-16)
 - ▶ UL 1577
 - ▶ $V_{ISO} = 5700$ V rms for 1 minute, SOIC (RW-16)
 - ▶ $V_{ISO} = 3000$ V rms for 1 minute, QSOP (RQ-16)
 - ▶ IEC/EN/CSA 62368-1
 - ▶ IEC/CSA 60601-1
 - ▶ IEC/CSA 61010-1
 - ▶ CQC GB4943.1
- ▶ ±8 kV IEC 61000-4-2 ESD protection across isolation barrier
- ▶ ±5 kV HBM ESD protection on input/output pins
- ▶ Fail-safe high (E1) or low (E0) options
- ▶ 16-lead, RoHS compliant, SOIC and QSOP packages
- ▶ Backward compatibility with
 - ▶ ADuM1400/ADuM1401/ADuM1402
 - ▶ ADuM2400/ADuM2401/ADuM2402
 - ▶ ADuM140E/ADuM141E/ADuM142E
 - ▶ ADuM240E/ADuM241E/ADuM242E
- ▶ AEC-Q100 qualified for automotive applications

APPLICATIONS

- ▶ Serial peripheral interface (SPI) data converter isolation
- ▶ RS-485 and controller area network with flexible data rate (CAN FD) industrial field bus isolation
- ▶ PWM controller signal isolation
- ▶ General-purpose multichannel isolation

GENERAL DESCRIPTION

The ADuM340E/ADuM341E/ADuM342E¹ are quad-channel digital isolators based on Analog Devices, Inc., iCoupler® technology. Combining high speed, complementary metal-oxide semiconductor (CMOS) and back-to-back monolithic air core transformer technology, these isolation components provide outstanding performance characteristics and meet CISPR 32/EN 55032 Class B limits at 5 Mbps. The maximum propagation delay is 10 ns with a pulse width distortion of less than 3 ns at 5 V operation. Channel matching is tight at 3.0 ns maximum.

The ADuM340E/ADuM341E/ADuM342E data channels are independent and are available in a variety of configurations with a withstand voltage rating of 5.7 kV rms (see [Figure 25](#)). The devices operate with the supply voltage on either side ranging from 2.25 V to 5.5 V, providing compatibility with lower voltage systems as well as enabling voltage translation functionality across the isolation barrier.

Two different fail-safe options are available, by which the outputs transition to a predetermined state when the input power supply is not applied.

¹ Protected by U.S. Patents 5,952,849; 6,873,065; 6,903,578; and 7,075,329. Other patents are pending.

TABLE OF CONTENTS

Features.....	1	Typical Performance Characteristics.....	21
Applications.....	1	Theory of Operation.....	23
General Description.....	1	Truth Table.....	24
Functional Block Diagrams.....	4	Applications Information.....	25
Specifications.....	5	PCB Layout.....	25
Electrical Specifications.....	5	Propagation Delay Related Parameters.....	25
Insulation Specifications.....	13	Jitter Measurement.....	25
Regulatory Information.....	16	Thermal Analysis.....	25
Recommended Operating Conditions.....	17	Insulation Lifetime.....	26
Absolute Maximum Ratings.....	18	Outline Dimensions.....	27
Electrostatic Discharge (ESD) Ratings.....	18	Ordering Guide.....	27
Thermal Characteristics.....	18	Evaluation Boards.....	28
ESD Caution.....	18	Automotive Products.....	28
Pin Configurations and Function Descriptions.....	19		

REVISION HISTORY**12/2025—Rev. B to Rev. C**

Changes to Features Section.....	1
Changed Electrical Characteristics—5 V Operation Section to Electrical Specifications Section.....	5
Added 5 V Operation Section.....	5
Change to Table 1 Title.....	5
Changed Switching Specifications Parameter to Timing Specifications Parameter, Table 1.....	5
Added Input Capacitance Parameter, Table 1.....	5
Changes to Title and ADuM340E Supply Current Parameter, Table 2.....	6
Changed Electrical Characteristics—3.3 V Operation Section to 3.3 V Operation Section.....	8
Change to Table 3 Title.....	8
Changed Switching Specifications Parameter to Timing Specifications Parameter, Table 3.....	8
Added Input Capacitance Parameter, Table 3.....	8
Changes to Title and ADuM340E Supply Current Parameter, Table 4.....	9
Changed Electrical Characteristics—2.5 V Operation Section to 2.5 V Operation Section.....	11
Change to Table 5 Title.....	11
Changed Switching Specifications Parameter to Timing Specifications Parameter, Table 5.....	11
Added Input Capacitance Parameter, Table 5.....	11
Changes to Title and ADuM340E Supply Current Parameter, Table 6.....	12
Changed Insulation and Safety Related Specifications Section to Insulation Specifications Section.....	13
Changes to Insulation Specifications Section and Table 7.....	13
Moved Figure 4.....	14
Changes to Figure 4 Caption and Table 8.....	14
Moved Figure 5.....	15
Changes to Figure 5 and Caption.....	15
Deleted Package Characteristics Section and Table 9; Renumbered Sequentially.....	15
Changes to Regulatory Information Section, Table 9, and Table 10.....	16
Deleted DIN V VDE V 0884-11 (VDE V 0884-11) Insulation Characteristics (Pending) Section, Table 12, and Table 13.....	16
Added Thermal Characteristics Section and Table 14.....	18
Changes to Table 17.....	20
Added Thermal Analysis Section.....	25
Changes to Insulation Lifetime Section.....	26

TABLE OF CONTENTS

Deleted Surface Tracking Section, Insulation Wear Out Section, Calculation and Use of Parameters
Example Section, and Figure 25.....26

Updated Outline Dimensions.....27

12/2023—Rev. A to Rev. B

Changes to Data Sheet Title.....1

Changes to Features Section.....1

Change to Note 12, Table 1.....5

Added Table 8; Renumbered Sequentially.....13

Changes to Table 9.....13

Changes to Table 10.....14

Added Table 11.....14

Changes to Table 12 Title.....14

Added Table 13.....14

Changes to Figure 4 Caption.....14

Added Figure 5; Renumbered Sequentially.....15

Added Table 17.....18

Updated Outline Dimensions.....27

Changes to Figure 28.....27

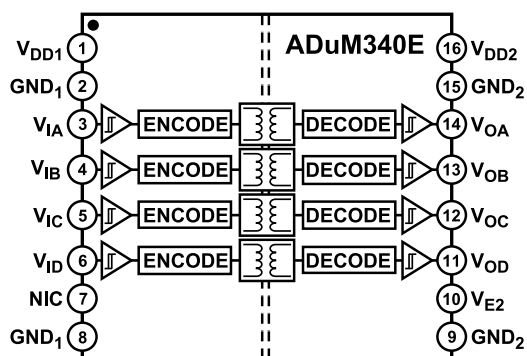
Changes to Ordering Guide.....27

8/2023—Rev. 0 to Rev. A

Changes to Ordering Guide.....27

1/2023—Revision 0: Initial Version

FUNCTIONAL BLOCK DIAGRAMS

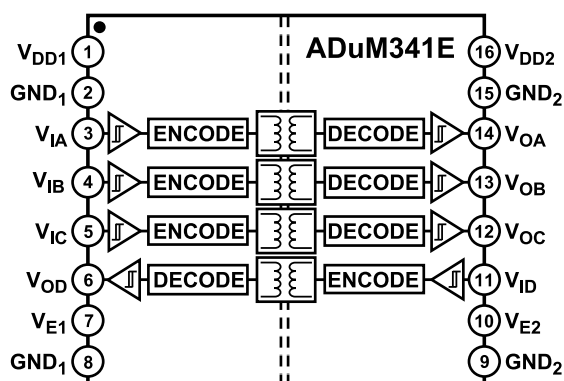


NOTES

1. NIC = NO INTERNAL CONNECTION. LEAVE THIS PIN FLOATING.

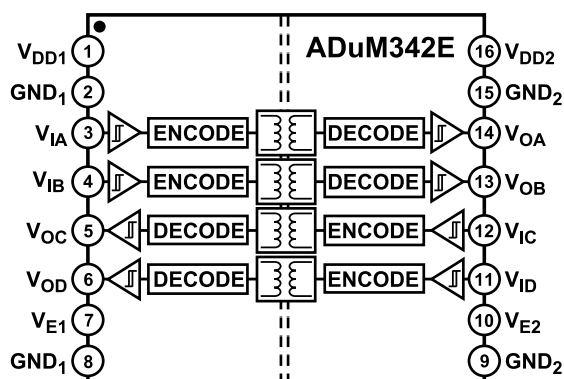
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Figure 1. ADuM340E Functional Block Diagram



002

Figure 2. ADuM341E Functional Block Diagram



003

Figure 3. ADuM342E Functional Block Diagram

SPECIFICATIONS

ELECTRICAL SPECIFICATIONS

5 V Operation

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = 5\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range of $4.5\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$, $4.5\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted. Supply currents are specified with 50% duty-cycle signals.

Table 1. Electrical Characteristics (5 V Operation)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
TIMING SPECIFICATIONS						
Pulse Width	PW	6.6			ns	Within pulse width distortion (PWD) limit
Data Rate		150			Mbps	Within PWD limit
Propagation Delay	t_{PHL} , t_{PLH}	3.5	6.2	10	ns	50% input to 50% output
Pulse Width Distortion	PWD		0.3	3	ns	$ t_{PLH} - t_{PHL} $
Change vs. Temperature			1.5		ps/ $^\circ\text{C}$	
Propagation Delay Skew	t_{PSK}			6.1	ns	Between any two units at the same temperature, voltage, and load
Channel Matching						
Codirectional	t_{PSKCD}		0.3	3.0	ns	
Opposing Direction	t_{PSKOD}		0.3	3.0	ns	
Jitter ¹						See the Jitter Measurement section
Random Jitter, RMS (1σ) ²	$t_{JIT(RJ)}$		7.19		ps	1 MHz clock input, all channels switching
Deterministic Jitter, Peak-to-Peak ^{3, 4}	$t_{JIT(DJ)}$		223		ps	100 Mbps, $2^{15} - 1$ PRBS input
Total Jitter, Peak-to-Peak, at Bit Error Rate (BER) 1×10^{-12}	$t_{JIT(TJ)}$					100 Mbps, $2^{15} - 1$ PRBS input ⁵
Without Crosstalk			292		ps	Single channel switching
With Crosstalk			559		ps	All channels switching
Output Enabled to High-Z	t_{PHZ} , t_{PLZ}	3	5.5	12	ns	Output high/low to high impedance
Output High-Z to Enabled	t_{PZH} , t_{PZL}	3	5.5	12	ns	Output high impedance to high/low
DC SPECIFICATIONS						
Input Threshold Voltage						V_{IX}, V_{EX}
Logic High	V_{IH}	$0.7 \times V_{DDX}$			V	
Logic Low	V_{IL}			$0.3 \times V_{DDX}$	V	
Input Hysteresis	V_{HYS}		0.85		V	$V_{IH} - V_{IL}$
Output Voltage						
Logic High	V_{OH}	$V_{DDX} - 0.1$	V_{DDX}		V	$I_{OX}^6 = -20\text{ }\mu\text{A}$, $V_{IX} = V_{IXH}^7$
		$V_{DDX} - 0.4$	$V_{DDX} - 0.2$		V	$I_{OX}^6 = -4\text{ mA}$, $V_{IX} = V_{IXH}^7$
Logic Low	V_{OL}		0.0	0.1	V	$I_{OX}^6 = 20\text{ }\mu\text{A}$, $V_{IX} = V_{IXL}^8$
			0.2	0.4	V	$I_{OX}^6 = 4\text{ mA}$, $V_{IX} = V_{IXL}^8$
Input Current per Channel	I_I	-10	+0.01	+10	μA	$0\text{ V} \leq V_{IX} \leq V_{DDX}$, $0\text{ V} \leq V_{EX} \leq V_{DDX}$
V_{E1} , V_{E2} Enable Input Pull-Up Current	I_{PU}	-10	-6		μA	$V_{EX} = 0\text{ V}$
Tristate Output Current per Channel	I_{OZ}	-10	+0.01	+10	μA	$0\text{ V} \leq V_{OX} \leq V_{DDX}$, $V_{EX} \leq V_{IL}$
Quiescent Supply Current						
ADuM340E						
$I_{DD1}(Q)$			0.61	0.85	mA	$V_I^9 = 0\text{ (E0)}, 1\text{ (E1)}^{10}$
$I_{DD2}(Q)$			1.5	2.3	mA	$V_I^9 = 0\text{ (E0)}, 1\text{ (E1)}^{10}$
$I_{DD1}(Q)$			7.6	11.2	mA	$V_I^9 = 1\text{ (E0)}, 0\text{ (E1)}^{10}$
$I_{DD2}(Q)$			3.3	5.1	mA	$V_I^9 = 1\text{ (E0)}, 0\text{ (E1)}^{10}$
ADuM341E						
$I_{DD1}(Q)$			0.8	1.3	mA	$V_I^9 = 0\text{ (E0)}, 1\text{ (E1)}^{10}$

SPECIFICATIONS

Table 1. Electrical Characteristics (5 V Operation) (Continued)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
ADuM342E	I_{DD2} (Q)		1.3	1.9	mA	$V_I^9 = 0$ (E0), 1 (E1) ¹⁰
	I_{DD1} (Q)		6.3	9.2	mA	$V_I^9 = 1$ (E0), 0 (E1) ¹⁰
	I_{DD2} (Q)		4.2	6	mA	$V_I^9 = 1$ (E0), 0 (E1) ¹⁰
	I_{DD1} (Q)		1.0	1.7	mA	$V_I^9 = 0$ (E0), 1 (E1) ¹⁰
	I_{DD2} (Q)		1.0	1.7	mA	$V_I^9 = 0$ (E0), 1 (E1) ¹⁰
	I_{DD1} (Q)		5.2	8.0	mA	$V_I^9 = 1$ (E0), 0 (E1) ¹⁰
	I_{DD2} (Q)		5.3	7.8	mA	$V_I^9 = 1$ (E0), 0 (E1) ¹⁰
Dynamic Supply Current						
Dynamic Input	I_{DDI} (D)		0.005		mA/Mbps	Inputs switching, 50% duty cycle
Dynamic Output	I_{DDO} (D)		0.015		mA/Mbps	Inputs switching, 50% duty cycle, $C_L = 0$ nF
Undervoltage Lockout	UVLO					
Positive V_{DDx} Threshold	V_{UVLO+}		2.0	2.2	V	Rising supply voltage enable threshold
Negative V_{DDx} Threshold	V_{UVLO-}	1.7	1.8		V	Falling supply voltage lockout threshold
V_{DDx} Hysteresis	V_{UVLO_HYS}		0.2		V	UVLO hysteresis
UVLO Release Time ¹¹	t_{UVLO}			60	μs	UVLO release delay after V_{UVLO+} threshold
AC SPECIFICATIONS						
Output Rise/Fall Time	t_R/t_F		2.5		ns	10% to 90%
Common-Mode Transient Immunity ^{11, 12}	$ CM_H $	100	180		kV/μs	$V_{IX} = V_{DDx}$, $V_{CM} = 1000$ V
	$ CM_L $	100	180		kV/μs	$V_{IX} = 0$ V, $V_{CM} = 1000$ V
Input Capacitance ¹³	C_I		4.0		pF	

¹ Jitter parameters are guaranteed by design and characterization. Values do not include stimulus jitter.

² This specification is measured over a population of ~100,000 edges.

³ Peak-to-peak jitter specifications include jitter due to PWD.

⁴ This specification is measured over a population of ~300,000 edges.

⁵ Using the following formula: $t_{JIT(TJ)} = 14 \times t_{JIT(RJ)} + t_{JIT(DJ)}$.

⁶ I_{Ox} is the Channel x output current, where x = A, B, C, or D.

⁷ V_{IXH} is the input side logic high.

⁸ V_{IXL} is the input side logic low.

⁹ V_I is the voltage input.

¹⁰ E0 refers to the ADuM340E0/ADuM341E0/ADuM342E0 models, and E1 refers to the ADuM340E1/ADuM341E1/ADuM342E1 models. See the [Ordering Guide](#) section.

¹¹ Guaranteed by design and not subject to production test.

¹² $|CM_H|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining the voltage output (V_O) < 0.8 V_{DDx} . $|CM_L|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O > 0.8$ V. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

¹³ Input capacitance is from any input data pin to the respective ground.

Table 2. Total Supply Current vs. Data Throughput (5 V Operation)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
SUPPLY CURRENT						
ADuM340E						
1 Mbps						
Supply Current Side 1	I_{DD1}		4.2	6.1	mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}		2.5	3.6	mA	$C_L = 0$ nF
25 Mbps						
Supply Current Side 1	I_{DD1}		4.6	6.4	mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}		3.9	5.3	mA	$C_L = 0$ nF
100 Mbps						
Supply Current Side 1	I_{DD1}		6.3	8.7	mA	$C_L = 0$ nF

SPECIFICATIONS

Table 2. Total Supply Current vs. Data Throughput (5 V Operation) (Continued)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Supply Current Side 2 ADuM341E 1 Mbps	I_{DD2}	8.5	10.9		mA	$C_L = 0$ nF
Supply Current Side 1	I_{DD1}	3.6	5.3		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	2.8	4.1		mA	$C_L = 0$ nF
25 Mbps						
Supply Current Side 1	I_{DD1}	4.4	6.0		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	4.0	5.6		mA	$C_L = 0$ nF
100 Mbps						
Supply Current Side 1	I_{DD1}	6.7	9.2		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	7.9	10.5		mA	$C_L = 0$ nF
ADuM342E 1 Mbps						
Supply Current Side 1	I_{DD1}	3.1	4.9		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	3.2	4.8		mA	$C_L = 0$ nF
25 Mbps						
Supply Current Side 1	I_{DD1}	4.1	6.1		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	4.2	5.9		mA	$C_L = 0$ nF
100 Mbps						
Supply Current Side 1	I_{DD1}	7.3	10.0		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	7.3	10.0		mA	$C_L = 0$ nF

SPECIFICATIONS

3.3 V Operation

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = 3.3\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $3.0\text{ V} \leq V_{DD1} \leq 3.6\text{ V}$, $3.0\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted. Supply currents are specified with 50% duty-cycle signals.

Table 3. Electrical Characteristics (3.3 V Operation)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
TIMING SPECIFICATIONS						
Pulse Width	PW	6.6			ns	Within PWD limit
Data Rate		150			Mbps	Within PWD limit
Propagation Delay	t_{PHL} , t_{PLH}	3.6	6.6	10	ns	50% input to 50% output
Pulse Width Distortion	PWD		0.5	3	ns	$ t_{PLH} - t_{PHL} $
Change vs. Temperature			1.5		ps/ $^\circ\text{C}$	
Propagation Delay Skew	t_{PSK}			7.5	ns	Between any two units at the same temperature, voltage, and load
Channel Matching						
Codirectional	t_{PSKCD}		0.5	3.0	ns	
Opposing Direction	t_{PSKOD}		0.5	3.0	ns	
Jitter ¹						See the Jitter Measurement section
Random Jitter, RMS (1σ) ²	$t_{JIT(RJ)}$		7.1		ps	1 MHz clock input
Deterministic Jitter, Peak-to-Peak ^{3, 4}	$t_{JIT(DJ)}$		243		ps	100 Mbps, 2 ¹⁵ – 1 PRBS input
Total Jitter, Peak-to-Peak, at Bit Error Rate (BER) 1×10^{-12}	$t_{JIT(TJ)}$					100 Mbps, 2 ¹⁵ – 1 PRBS input ⁵
Without Crosstalk			318		ps	Single channel switching
With Crosstalk			444		ps	All channels switching
Output Enabled to High-Z	t_{PHZ} , t_{PLZ}	3	5	12	ns	Output high/low to high Impedance
Output High-Z to Enabled	t_{PZH} , t_{PZL}	3	5	12	ns	Output high impedance to high/low
DC SPECIFICATIONS						
Input Threshold Voltage						V_{IX} , V_{EX}
Logic High	V_{IH}	$0.7 \times V_{DDX}$			V	
Logic Low	V_{IL}			$0.3 \times V_{DDX}$	V	
Input Hysteresis	V_{HYS}		0.7		V	$V_{IH} - V_{IL}$
Output Voltage						
Logic High	V_{OH}	$V_{DDX} - 0.1$	V_{DDX}		V	$I_{OX}^6 = -20\text{ }\mu\text{A}$, $V_{IX} = V_{IXH}^7$
		$V_{DDX} - 0.4$	$V_{DDX} - 0.2$		V	$I_{OX}^6 = -2\text{ mA}$, $V_{IX} = V_{IXH}^7$
Logic Low	V_{OL}		0.0	0.1	V	$I_{OX}^6 = 20\text{ }\mu\text{A}$, $V_{IX} = V_{IXL}^8$
			0.2	0.4	V	$I_{OX}^6 = 2\text{ mA}$, $V_{IX} = V_{IXL}^8$
Input Current per Channel	I_I	-10	+0.01	+10	μA	$0\text{ V} \leq V_{IX} \leq V_{DDX}$, $0\text{ V} \leq V_{EX} \leq V_{DDX}$
V_{E2} Enable Input Pull-Up Current	I_{PU}	-10	-4		μA	$V_{E2} = 0\text{ V}$
Tristate Output Current per Channel	I_{OZ}	-10	+0.01	+10	μA	$0\text{ V} \leq V_{OX} \leq V_{DDX}$, $V_{EX} \leq V_{IL}$
Quiescent Supply Current						
ADuM340E						
$I_{DD1(Q)}$			0.6	0.82	mA	$V_I^9 = 0\text{ (E0)}$, 1 (E1) ¹⁰
$I_{DD2(Q)}$			1.4	2.2	mA	$V_I^9 = 0\text{ (E0)}$, 1 (E1) ¹⁰
$I_{DD1(Q)}$			7.5	11.0	mA	$V_I^9 = 1\text{ (E0)}$, 0 (E1) ¹⁰
$I_{DD2(Q)}$			3.2	5.0	mA	$V_I^9 = 1\text{ (E0)}$, 0 (E1) ¹⁰
ADuM341E						
$I_{DD1(Q)}$			0.8	1.3	mA	$V_I^9 = 0\text{ (E0)}$, 1 (E1) ¹⁰
$I_{DD2(Q)}$			1.2	1.8	mA	$V_I^9 = 0\text{ (E0)}$, 1 (E1) ¹⁰
$I_{DD1(Q)}$			6.6	8.8	mA	$V_I^9 = 1\text{ (E0)}$, 0 (E1) ¹⁰

SPECIFICATIONS

Table 3. Electrical Characteristics (3.3 V Operation) (Continued)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
ADuM342E	$I_{DD2(Q)}$		4.1	5.9	mA	$V_I^9 = 1 (E0), 0 (E1)^{10}$
	$I_{DD1(Q)}$		0.9	1.6	mA	$V_I^9 = 0 (E0), 1 (E1)^{10}$
	$I_{DD2(Q)}$		1.0	1.6	mA	$V_I^9 = 0 (E0), 1 (E1)^{10}$
	$I_{DD1(Q)}$		5.1	7.6	mA	$V_I^9 = 1 (E0), 0 (E1)^{10}$
	$I_{DD2(Q)}$		5.2	7.6	mA	$V_I^9 = 1 (E0), 0 (E1)^{10}$
Dynamic Supply Current						
Dynamic Input	$I_{DDI(D)}$		0.004		mA/Mbps	Inputs switching, 50% duty cycle
Dynamic Output	$I_{DDO(D)}$		0.009		mA/Mbps	Inputs switching, 50% duty cycle
Undervoltage Lockout	UVLO					
Positive V_{DDx} Threshold	V_{UVLO+}		2.0	2.2	V	Rising supply voltage enable threshold
Negative V_{DDx} Threshold	V_{UVLO-}	1.7	1.8		V	Falling supply voltage lockout threshold
V_{DDx} Hysteresis	V_{UVLO_HYS}		0.2		V	UVLO hysteresis
UVLO Release Time ¹¹	t_{UVLO}			60	μs	UVLO release delay after V_{UVLO+} threshold
AC SPECIFICATIONS						
Output Rise/Fall Time	t_R/t_F		2.5		ns	10% to 90%
Common-Mode Transient Immunity ^{11, 12}	$ CM_H $	100	180		kV/μs	$V_{IX} = V_{DDx}$, $V_{CM} = 1000$ V, transient magnitude = 800 V
	$ CM_L $	100	180		kV/μs	$V_{IX} = 0$ V, $V_{CM} = 1000$ V, transient magnitude = 800 V
Input Capacitance ¹³	C_I		4.0		pF	

¹ Jitter parameters are guaranteed by design and characterization. Values do not include stimulus jitter.

² This specification is measured over a population of ~100,000 edges.

³ Peak-to-peak jitter specifications include jitter due to PWD.

⁴ This specification is measured over a population of ~300,000 edges.

⁵ Using the following formula: $t_{JIT(TJ)} = 14 \times t_{JIT(RJ)} + t_{JIT(DJ)}$.

⁶ I_{Ox} is the Channel x output current, where x = A, B, C, or D.

⁷ V_{IXH} is the input side logic high.

⁸ V_{IXL} is the input side logic low.

⁹ V_I is the voltage input.

¹⁰ E0 refers to ADuM340E0/ADuM341E0/ADuM342E0 models, and E1 refers to ADuM340E1/ADuM341E1/ADuM342E1 models. See the [Ordering Guide](#) section.

¹¹ Guaranteed by design and not subject to production test.

¹² $|CM_H|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining the voltage output (V_O) > 0.8 V_{DDx} . $|CM_L|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining V_O > 0.8 V. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

¹³ Input capacitance is from any input data pin to the respective ground.

Table 4. Total Supply Current vs. Data Throughput (3.3 V Operation)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
SUPPLY CURRENT						
ADuM340E						
1 Mbps						
Supply Current Side 1	I_{DD1}		4.1	6.0	mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}		2.4	3.5	mA	$C_L = 0$ nF
25 Mbps						
Supply Current Side 1	I_{DD1}		4.5	6.2	mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}		3.4	4.6	mA	$C_L = 0$ nF
100 Mbps						
Supply Current Side 1	I_{DD1}		5.8	7.5	mA	$C_L = 0$ nF

SPECIFICATIONS

Table 4. Total Supply Current vs. Data Throughput (3.3 V Operation) (Continued)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Supply Current Side 2 ADuM341E	I_{DD2}	6.3	8.8		mA	$C_L = 0$ nF
1 Mbps						
Supply Current Side 1	I_{DD1}	3.7	4.9		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	2.7	3.9		mA	$C_L = 0$ nF
25 Mbps						
Supply Current Side 1	I_{DD1}	4.3	5.4		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	3.5	4.9		mA	$C_L = 0$ nF
100 Mbps						
Supply Current Side 1	I_{DD1}	6.2	7.5		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	6.1	8.4		mA	$C_L = 0$ nF
ADuM342E						
1 Mbps						
Supply Current Side 1	I_{DD1}	3.1	4.7		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	3.2	4.7		mA	$C_L = 0$ nF
25 Mbps						
Supply Current Side 1	I_{DD1}	3.7	5.4		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	3.8	5.4		mA	$C_L = 0$ nF
100 Mbps						
Supply Current Side 1	I_{DD1}	6.0	8.5		mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}	5.9	8.1		mA	$C_L = 0$ nF

SPECIFICATIONS

2.5 V Operation

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = 2.5\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $2.25\text{ V} \leq V_{DD1} \leq 2.75\text{ V}$, $2.25\text{ V} \leq V_{DD2} \leq 2.75\text{ V}$, $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted. Supply currents are specified with 50% duty-cycle signals.

Table 5. Electrical Characteristics (2.5 V Operation)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
TIMING SPECIFICATIONS						
Pulse Width	PW	10			ns	Within PWD limit
Data Rate		100			Mbps	Within PWD limit
Propagation Delay	t_{PHL} , t_{PLH}	4.1	7.2	14	ns	50% input to 50% output
Pulse Width Distortion	PWD		0.3	4.5	ns	$ t_{PLH} - t_{PHL} $
Change vs. Temperature			1.5		ps/ $^\circ\text{C}$	
Propagation Delay Skew	t_{PSK}			6.8	ns	Between any two units at the same temperature, voltage, and load
Channel Matching						
Codirectional	t_{PSKCD}		0.4	5.0	ns	
Opposing Direction	t_{PSKOD}		0.4	5.0	ns	
Jitter ¹						See the Jitter Measurement section
Random Jitter, RMS (1σ) ²	$t_{JIT(RJ)}$		8.58		ps	1 MHz clock input
Deterministic Jitter, Peak to Peak ^{3, 4}	$t_{JIT(DJ)}$		222		ps	100 Mbps, $2^{15} - 1$ PRBS
Total Jitter, Peak to Peak, at Bit Error Rate (BER) 1×10^{-12}	$t_{JIT(TJ)}$					100 Mbps, $2^{15} - 1$ PRBS ⁵
Without Crosstalk			295		ps	Single channel switching
With Crosstalk			450		ps	All channels switching
Output Enabled to High-Z	t_{PHZ} , t_{PLZ}		6	20	ns	Output high/low to high impedance
Output High-Z to Enabled	t_{PZH} , t_{PZL}		6	20	ns	Output high impedance to high/low
DC SPECIFICATIONS						
Input Threshold Voltage						
Logic High	V_{IH}	$0.7 \times V_{DDX}$			V	
Logic Low	V_{IL}			$0.3 \times V_{DDX}$	V	
Input Hysteresis	V_{HYS}		0.65		V	$V_{IH} - V_{IL}$
Output Voltage						
Logic High	V_{OH}	$V_{DDX} - 0.1$	V_{DDX}		V	$I_{OX}^6 = -20\text{ }\mu\text{A}$, $V_{IX} = V_{IXH}^7$
		$V_{DDX} - 0.4$	$V_{DDX} - 0.2$		V	$I_{OX}^6 = -2\text{ mA}$, $V_{IX} = V_{IXH}^7$
Logic Low	V_{OL}		0.0	0.1	V	$I_{OX}^6 = 20\text{ }\mu\text{A}$, $V_{IX} = V_{IXL}^8$
			0.2	0.4	V	$I_{OX}^6 = 2\text{ mA}$, $V_{IX} = V_{IXL}^8$
Input Current per Channel	I_I	-10	+0.01	+10	μA	$0\text{ V} \leq V_{IX} \leq V_{DDX}$
V_{E2} Enable Input Pull-Up Current	I_{PU}	-10	-3		μA	$V_{E2} = 0\text{ V}$
Tristate Output Current per Channel	I_{OZ}	-10	+0.01	+10	μA	$0\text{ V} \leq V_{OX} \leq V_{DDX}$, $V_{EX} \leq V_{IL}$
Quiescent Supply Current						
ADuM340E						
$I_{DD1}(Q)$			0.6	0.82	mA	$V_I^9 = 0\text{ (E0)}, 1\text{ (E1)}^{10}$
$I_{DD2}(Q)$			1.4	2.2	mA	$V_I^9 = 0\text{ (E0)}, 1\text{ (E1)}^{10}$
$I_{DD1}(Q)$			7.6	10.4	mA	$V_I^9 = 1\text{ (E0)}, 0\text{ (E1)}^{10}$
$I_{DD2}(Q)$			3.2	4.8	mA	$V_I^9 = 1\text{ (E0)}, 0\text{ (E1)}^{10}$
ADuM341E						
$I_{DD1}(Q)$			0.8	1.3	mA	$V_I^9 = 0\text{ (E0)}, 1\text{ (E1)}^{10}$
$I_{DD2}(Q)$			1.2	2.0	mA	$V_I^9 = 0\text{ (E0)}, 1\text{ (E1)}^{10}$
$I_{DD1}(Q)$			6.6	8.9	mA	$V_I^9 = 1\text{ (E0)}, 0\text{ (E1)}^{10}$

SPECIFICATIONS

Table 5. Electrical Characteristics (2.5 V Operation) (Continued)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
ADuM342E	$I_{DD2(Q)}$		4.1	5.9	mA	$V_I^9 = 1$ (E0), 0 (E1) ¹⁰
	$I_{DD1(Q)}$		1.0	1.6	mA	$V_I^9 = 0$ (E0), 1 (E1) ¹⁰
	$I_{DD2(Q)}$		1.0	1.6	mA	$V_I^9 = 0$ (E0), 1 (E1) ¹⁰
	$I_{DD1(Q)}$		5.1	8.1	mA	$V_I^9 = 1$ (E0), 0 (E1) ¹⁰
	$I_{DD2(Q)}$		5.2	7.6	mA	$V_I^9 = 1$ (E0), 0 (E1) ¹⁰
Dynamic Supply Current						
Dynamic Input	$I_{DDI(D)}$		0.004		mA/Mbps	Inputs switching, 50% duty cycle
Dynamic Output	$I_{DDO(D)}$		0.008		mA/Mbps	Inputs switching, 50% duty cycle
Undervoltage Lockout						
Positive V_{DDx} Threshold	V_{UVLO+}		2.0	2.2	V	Rising supply voltage enable threshold
Negative V_{DDx} Threshold	V_{UVLO-}	1.7	1.8		V	Falling supply voltage lockout threshold
V_{DDx} Hysteresis	V_{UVLO_HYS}		0.2		V	UVLO hysteresis
UVLO Release Time ¹¹	t_{UVLO}			60	μs	UVLO release delay after V_{UVLO+} threshold
AC SPECIFICATIONS						
Output Rise/Fall Time	t_R/t_F		2.5		ns	10% to 90%
Common-Mode Transient Immunity ^{11, 12}	$ CM_H $	100	180		kV/μs	$V_{IX} = V_{DDx}$, $V_{CM} = 1000$ V, transient magnitude = 800 V
	$ CM_L $	100	180		kV/μs	$V_{IX} = 0$ V, $V_{CM} = 1000$ V, transient magnitude = 800 V
Input Capacitance ¹³	C_I		4.0		pF	

¹ Jitter parameters are guaranteed by design and characterization. Values do not include stimulus jitter.

² This specification is measured over a population of ~100,000 edges.

³ Peak-to-peak jitter specifications include jitter due to PWD.

⁴ This specification is measured over a population of ~300,000 edges.

⁵ Using the following formula: $t_{JIT(TJ)} = 14 \times t_{JIT(RJ)} + t_{JIT(DJ)}$.

⁶ I_{Ox} is the Channel x output current, where x = A, B, C, or D.

⁷ V_{IXH} is the input side logic high.

⁸ V_{IXL} is the input side logic low.

⁹ V_I is the voltage input.

¹⁰ E0 refers to ADuM340E0/ADuM341E0/ADuM342E0 models, and E1 refers to ADuM340E1/ADuM341E1/ADuM342E1 models. See the [Ordering Guide](#) section.

¹¹ Guaranteed by design and not subject to production test.

¹² $|CM_H|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining the voltage output (V_O) > 0.8 V_{DDx} . $|CM_L|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining V_O > 0.8 V. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

¹³ Input capacitance is from any input data pin to the respective ground.

Table 6. Total Supply Current vs. Data Throughput (2.5 V Operation)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
SUPPLY CURRENT						
ADuM340E						
1 Mbps						
Supply Current Side 1	I_{DD1}		4.0	5.9	mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}		2.4	3.5	mA	$C_L = 0$ nF
25 Mbps						
Supply Current Side 1	I_{DD1}		4.5	6.1	mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}		3.1	4.3	mA	$C_L = 0$ nF
100 Mbps						
Supply Current Side 1	I_{DD1}		5.6	7.3	mA	$C_L = 0$ nF

SPECIFICATIONS

Table 6. Total Supply Current vs. Data Throughput (2.5 V Operation) (Continued)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Supply Current Side 2 ADuM341E 1 Mbps	I_{DD2}		5.4	7.4	mA	$C_L = 0$ nF
Supply Current Side 1	I_{DD1}		3.7	4.9	mA	$C_L = 0$ nF
Supply Current Side 2 25 Mbps	I_{DD2}		2.7	3.9	mA	$C_L = 0$ nF
Supply Current Side 1	I_{DD1}		4.2	5.6	mA	$C_L = 0$ nF
Supply Current Side 2 100 Mbps	I_{DD2}		3.3	4.9	mA	$C_L = 0$ nF
Supply Current Side 1	I_{DD1}		5.8	7.6	mA	$C_L = 0$ nF
Supply Current Side 2 ADuM342E 1 Mbps	I_{DD2}		5.4	8.4	mA	$C_L = 0$ nF
Supply Current Side 1	I_{DD1}		3.1	4.7	mA	$C_L = 0$ nF
Supply Current Side 2 25 Mbps	I_{DD2}		3.2	4.7	mA	$C_L = 0$ nF
Supply Current Side 1	I_{DD1}		3.6	5.3	mA	$C_L = 0$ nF
Supply Current Side 2 100 Mbps	I_{DD2}		3.7	5.3	mA	$C_L = 0$ nF
Supply Current Side 1	I_{DD1}		5.4	7.5	mA	$C_L = 0$ nF
Supply Current Side 2	I_{DD2}		5.5	7.5	mA	$C_L = 0$ nF

INSULATION SPECIFICATIONS

The ADuM340E/ADuM341E/ADuM342E are suitable for safe electrical insulation only within the safety limiting ratings. Compliance with the safety limiting ratings must be ensured by means of suitable protective circuits.

Table 7. RW-16 Wide-Body [SOIC_W] Package Insulation Characteristics

Parameter	Symbol	Value	Unit	Test Conditions/Comments
GENERAL				
Minimum External Clearance Distance	CLR	7.8	mm	Measured from input terminals to output terminals, shortest distance through air per IEC 60664-1
Minimum External Creepage Distance	CRP	7.8	mm	Measured from input terminals to output terminals, shortest distance along body per IEC 60664-1
Distance Through Insulation	DTI	34	μm	Minimum internal
Comparative Tracking Index	CTI	>600	V	Per IEC 60112
Material Group	I			Per IEC 60664-1
Overvoltage Category per IEC 60664-1		I to IV		Rated mains voltage ≤ 150V rms
		I to IV		Rated mains voltage ≤ 300V rms
		I to III		Rated mains voltage ≤ 600V rms
SAFETY LIMITING VALUES				
Maximum Ambient Safety Temperature	T_S	150	°C	
Maximum Junction Temperature, Safety	$T_{JMAX,S}$	150	°C	Maximum junction temperature for isolation barrier safety
Maximum Total Power Dissipation	P_{TOT}	1.92	W	$T_A \leq 25^\circ\text{C}$, $P_{TOT} = P_{SI} = P_{SO}$
Derating Above Ambient		15.36	mW/°C	$T_A > 25^\circ\text{C}$, see Figure 4
Junction-to-Air Thermal Impedance	θ_{JA}	45	°C/W	See Table 14
IEC 60747-17 (REINFORCED INSULATION)				
Maximum Repetitive Peak Isolation Voltage	V_{IORM}	1173	V peak	

SPECIFICATIONS

Table 7. RW-16 Wide-Body [SOIC_W] Package Insulation Characteristics (Continued)

Parameter	Symbol	Value	Unit	Test Conditions/Comments
Maximum Isolation Working Voltage	V_{IOWM}	829	V rms	AC voltage, end of life test, $f = 60$ Hz
		1173	V peak	DC voltage
Maximum Transient Isolation Voltage	V_{IOTM}	8000	V peak	$V_{TEST} = 1.2 \times V_{IOTM}$, $t = 1$ s (100% production)
Maximum Impulse Voltage	V_{IMP}	8000	V peak	Surge voltage in air, waveform per IEC 61000-4-5
Maximum Surge Isolation Voltage	V_{IOSM}	16000	V peak	$V_{TEST} \geq 1.3 \times V_{IMP}$ minimum 10 kV (type test), tested in oil, waveform per IEC 61000-4-5
Apparent Charge	q_{pd}	≤ 5	pC	Method a (sample test), $V_{ini} = V_{IOTM}$, $t_{ini} = 60$ s, $V_{pd(m)} = 1.6 \times V_{IORM}$, $t_m = 10$ s Method b1 (100% production), $V_{ini} = 1.2 \times V_{IOTM}$, $t_{ini} = 1$ s, $V_{pd(m)} = 1.875 \times V_{IORM}$, $t_m = 1$ s
Resistance (Input to Output) ¹	R_{IO}	$>10^{11}$	Ω	$T_A = 25^\circ\text{C}$, $V_{TEST} = 500$ V dc, $t = 60$ s
	R_{IO_S}	$>10^9$	Ω	$T_A = T_S$, $V_{TEST} = 500$ V dc, $t = 60$ s
Capacitance (Input to Output) ¹	C_{IO}	0.85	pF	$f_{TEST} = 1$ MHz
Climate Category		40/125/21		
Pollution Degree		2		Per IEC 60664-1
UL 1577				
Maximum Withstanding Isolation Voltage	V_{ISO}	5700	V rms	$V_{TEST} = 1.2 \times V_{ISO}$, $t = 1$ s (100% production)

¹ Device measured as a 2-terminal device with Pin 1 to Pin 8 connected and Pin 9 to Pin 16 connected.

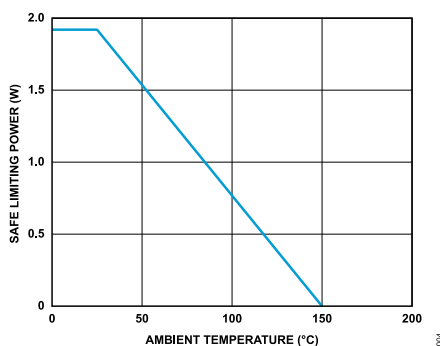


Figure 4. Thermal Derating Curve for 16-Lead Wide Body SOIC [SOIC_W] (RW-16), Dependence of Safety Limiting Power with Ambient Temperature per IEC 60747-17

Table 8. RQ-16 [QSOP] Package Insulation Characteristics

Parameter	Symbol	Value	Unit	Test Conditions/Comments
GENERAL				
Minimum External Clearance Distance	CLR	3.2	mm	Measured from input terminals to output terminals, shortest distance through air per IEC 60664-1
Minimum External Creepage Distance	CRP	3.2	mm	Measured from input terminals to output terminals, shortest distance along body per IEC 60664-1
Distance Through Insulation	DTI	34	μm	Minimum internal
Comparative Tracking Index	CTI	>600	V	Per IEC 60112
Material Group		I		Per IEC 60664-1
Overvoltage Category per IEC 60664-1		I to III		Rated mains voltage ≤ 150 V rms
		I to III		Rated mains voltage ≤ 300 V rms
SAFETY LIMITING VALUES				
Maximum Ambient Safety Temperature	T_S	150	$^\circ\text{C}$	

SPECIFICATIONS

Table 8. RQ-16 [QSOP] Package Insulation Characteristics (Continued)

Parameter	Symbol	Value	Unit	Test Conditions/Comments
Maximum Junction Temperature, Safety	$T_{JMAX,S}$	150	°C	Maximum junction temperature for isolation barrier safety
Maximum Total Power Dissipation	P_{TOT}	1.62	W	$T_A \leq 25^\circ\text{C}$, $P_{TOT} = P_{SI} = P_{SO}$
Derating Above Ambient		12.96	mW/°C	$T_A > 25^\circ\text{C}$, see Figure 5
Junction-to-Air Thermal Impedance	θ_{JA}	77	°C/W	See Table 14
IEC 60747-17 (REINFORCED INSULATION)				
Maximum Repetitive Peak Isolation Voltage	V_{IORM}	566	V peak	
Maximum Isolation Working Voltage	V_{IOWM}	400	V rms	AC voltage, end of life test, $f = 60\text{ Hz}$
		566	V peak	DC voltage
Maximum Transient Isolation Voltage	V_{IOTM}	4242	V peak	$V_{TEST} = 1.2 \times V_{IOTM}$, $t = 1\text{ s}$ (100% production)
Maximum Impulse Voltage	V_{IMP}	4000	V peak	Surge voltage in air, waveform per IEC 61000-4-5
Maximum Surge Isolation Voltage	V_{IOSM}	10000	V peak	$V_{TEST} \geq 1.3 \times V_{IMP}$ minimum 10 kV (type test), tested in oil, waveform per IEC 61000-4-5
Apparent Charge	q_{pd}	≤ 5	pC	Method a (sample test), $V_{ini} = V_{IOTM}$, $t_{ini} = 60\text{ s}$, $V_{pd(m)} = 1.6 \times V_{IORM}$, $t_m = 10\text{ s}$ Method b1 (100% production), $V_{ini} = 1.2 \times V_{IOTM}$, $t_{ini} = 1\text{ s}$, $V_{pd(m)} = 1.875 \times V_{IORM}$, $t_m = 1\text{ s}$
Resistance (Input to Output) ¹	R_{IO}	$> 10^{11}$	Ω	$T_A = 25^\circ\text{C}$, $V_{TEST} = 500\text{ V dc}$, $t = 60\text{ s}$
	R_{IO_S}	$> 10^9$	Ω	$T_A = T_S$, $V_{TEST} = 500\text{ V dc}$, $t = 60\text{ s}$
Capacitance (Input to Output) ¹	C_{IO}	0.85	pF	$f_{TEST} = 1\text{ MHz}$
Climate Category		40/125/21		
Pollution Degree		2		Per IEC 60664-1
UL 1577				
Maximum Withstanding Isolation Voltage	V_{ISO}	3000	V rms	$V_{TEST} = 1.2 \times V_{ISO}$, $t = 1\text{ s}$ (100% production)

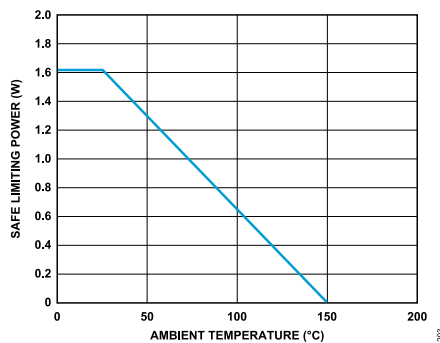
¹ Device measured as a 2-terminal device with Pin 1 to Pin 8 connected and Pin 9 to Pin 16 connected.

Figure 5. Thermal Derating Curve for 16-Lead QSOP (RQ-16), Dependence of Safety Limiting Power with Ambient Temperature per IEC 60747-17

SPECIFICATIONS

REGULATORY INFORMATION

The ADuM340E/ADuM341E/ADuM342E RW-16 and RQ-16 have been approved by the organizations listed in [Table 9](#) and [Table 10](#). Copies of the relevant certifications are available at [Safety and Regulatory Certification for Digital Isolation](#).

Table 9. RW-16 Wide-Body [SOIC_W] Package

Regulatory Agency	Standard Certification/Approval	File
UL	UL 1577 Single protection, 5700 V rms isolation voltage	File E214100
TÜV Süd	DIN EN IEC 60747-17 (VDE 0884-17) Reinforced insulation at 1173 V peak EN 62368-1 Basic Insulation at 780 V rms Reinforced Insulation at 390 V rms	Certificate B 056232 0029 Certificate B 056232 0033
CSA ¹	IEC / EN / CSA 62368-1 Basic insulation at 780 V rms Reinforced insulation at 390 V rms IEC / CSA 60601-1 2 MOPP at 237.5 V rms IEC / CSA 61010-1 Basic insulation at 600 V rms Reinforced insulation at 300 V rms	File 205078
CQC	CQC GB4943.1 Basic insulation at 780 V rms Reinforced insulation at 390 V rms	Certificate CQC25001466407

¹ Working voltages are quoted for Pollution Degree 2, Material Group III and Overvoltage Category II except where otherwise specified. The ADuM340E/ADuM341E/ADuM342E case material has been evaluated by CSA as Material Group I.

Table 10. RQ-16 [QSOP] Package

Regulatory Agency	Standard Certification/Approval	File
UL	UL 1577 Single protection, 3000 V rms isolation voltage	E214100
TÜV Süd	DIN EN IEC 60747-17 (VDE 0884-17) Reinforced insulation at 566 V peak EN 62368-1 Basic Insulation at 320 V rms Reinforced Insulation at 160 V rms	Certificate B 056232 0029 Certificate B 056232 0033
CSA ¹	IEC / EN / CSA 62368-1 Basic insulation at 320 V rms Reinforced insulation at 160 V rms IEC / CSA 60601-1 1 MOPP at 150 V rms IEC / CSA 61010-1 Basic insulation at 300 V rms Reinforced insulation at 150 V rms	File 205078

SPECIFICATIONS

Table 10. RQ-16 [QSOP] Package (Continued)

Regulatory Agency	Standard Certification/Approval	File
CQC	CQC GB4943.1 Basic insulation at 300 V rms Reinforced insulation at 150 V rms	Certificate CQC25001466831

¹ Working voltages are quoted for Pollution Degree 2, Material Group III and Overvoltage Category II except where otherwise specified. The ADuM340E/ADuM341E/ADuM342E case material has been evaluated by CSA as Material Group I.

RECOMMENDED OPERATING CONDITIONS

Table 11. Recommended Operating Conditions

Parameter	Symbol	Rating
Operating Temperature	T_A	-40°C to +125°C
Supply Voltages		
V_{DD1}		2.25 V to 5.5 V
V_{DD2}		2.25 V to 5.5 V
Input Signal Rise and Fall Times		1.0 ms

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 12. Absolute Maximum Ratings

Parameter	Rating
Supply Voltages	
V_{DD1} to GND_1	-0.5 V to +7.0 V
V_{DD2} to GND_2	-0.5 V to +7.0 V
Input Voltages (V_{IA} , V_{IB} , V_{IC} , V_{ID} , V_{E1} , V_{E2}) ¹	-0.5 V to $V_{DD1} + 0.5$ V
Output Voltages (V_{OA} , V_{OB} , V_{OC} , V_{OD}) ²	-0.5 V to $V_{DDO} + 0.5$ V
Average Output Current per Pin ³	
Side 1 Output Current (I_{O1})	-10 mA to +10 mA
Side 2 Output Current (I_{O2})	-10 mA to +10 mA
Common-Mode Transients ⁴	-300 kV/ μs to +300 kV/ μs
Storage Temperature (T_{ST}) Range	-65°C to +150°C
Ambient Operating Temperature (T_A) Range	-40°C to +125°C
Moisture Sensitivity Level	MSL3

¹ V_{DD1} is the input side supply voltage.

² V_{DDO} is the output side supply voltage.

³ See Figure 4 for the maximum rated current values for various ambient temperatures.

⁴ Refers to the common-mode transients across the insulation barrier. Common-mode transients exceeding the absolute maximum ratings may cause latchup or permanent damage.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

ELECTROSTATIC DISCHARGE (ESD) RATINGS

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

Human body model (HBM) per ANSI/ESDA/JEDEC JS-001.

Charged device model (CDM) per ANSI/ESDA/JEDEC JS-002.

International Electrotechnical Commission (IEC) electromagnetic compatibility: Part 4-2 (IEC) per IEC 61000-4-2.

ESD Ratings for ADuM340E/ADuM341E/ADuM342E

Table 13. ADuM340E/ADuM341E/ADuM342E, 16-Lead SOIC_W

ESD Model	Withstand Threshold (V)	Class
HBM ¹	±5000	3A
CDM ¹	±1250	C3
IEC ²	±8000	Level 4

¹ With respect to local V_{DDx} and GND_x pins.

² Across the isolation barrier between GND_1 and GND_2 .

THERMAL CHARACTERISTICS

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

Thermal resistance and characterization parameter values specified in Table 14 are defined and calculated based on the JEDEC JESD51 standards. For more details on their definition and usage, see JEDEC JESD51-12 and the Thermal Analysis section.

Table 14. Package Thermal Data

Package Type ¹	θ_{JA}	θ_{JB}	Ψ_{JB}	Ψ_{JT}	Unit
SOIC_W (RW-16)	64.89	43.86	42.61	5.72	°C/W
QSOP (RQ-16)	77.69	43.19	43.58	0.92	°C/W

¹ Thermal impedance simulated values are based on JEDEC 2S2P thermal test board with no vias and still air.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

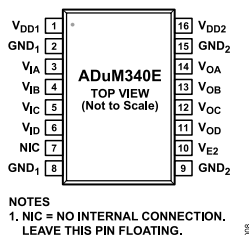


Figure 6. ADuM340E Pin Configuration

Table 15. ADuM340E Pin Function Descriptions

Pin No.	Mnemonic	Description
1	V _{DD1}	Supply Voltage for Isolator Side 1. This pin requires a 0.1 μ F bypass capacitor.
2, 8	GND ₁	Ground Reference for Isolator Side 1.
3	V _{IA}	Logic Input A.
4	V _{IB}	Logic Input B.
5	V _{IC}	Logic Input C.
6	V _{ID}	Logic Input D.
7	NIC	No Internal Connection. Leave this pin floating.
9, 15	GND ₂	Ground Reference for Isolator Side 2.
10	V _{E2}	Output Enable 2. Active high logic input. When V _{E2} is high or disconnected, the V _{OA} , V _{OB} , V _{OC} , and V _{OD} outputs are enabled. When V _{E2} is low, the V _{OA} , V _{OB} , V _{OC} , and V _{OD} outputs are disabled to the high-Z state.
11	V _{OD}	Logic Output D.
12	V _{OC}	Logic Output C.
13	V _{OB}	Logic Output B.
14	V _{OA}	Logic Output A.
16	V _{DD2}	Supply Voltage for Isolator Side 2. This pin requires a 0.1 μ F bypass capacitor.

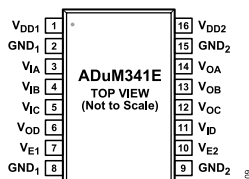


Figure 7. ADuM341E Pin Configuration

Table 16. ADuM341E Pin Function Descriptions

Pin No.	Mnemonic	Description
1	V _{DD1}	Supply Voltage for Isolator Side 1. This pin requires a 0.1 μ F bypass capacitor.
2, 8	GND ₁	Ground Reference for Isolator Side 1.
3	V _{IA}	Logic Input A.
4	V _{IB}	Logic Input B.
5	V _{IC}	Logic Input C.
6	V _{OD}	Logic Output D.
7	V _{E1}	Output Enable 1. Active high logic input. When V _{E1} is high or disconnected, the V _{OD} output is enabled. When V _{E1} is low, the V _{OD} output is disabled to the high-Z state.
9, 15	GND ₂	Ground Reference for Isolator Side 2.
10	V _{E2}	Output Enable 2. Active high logic input. When V _{E2} is high or disconnected, the V _{OA} , V _{OB} , and V _{OC} outputs are enabled. When V _{E2} is low, the V _{OA} , V _{OB} , and V _{OC} outputs are disabled to the high-Z state.
11	V _{ID}	Logic Input D.
12	V _{OC}	Logic Output C.
13	V _{OB}	Logic Output B.
14	V _{OA}	Logic Output A.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

Table 16. ADuM341E Pin Function Descriptions (Continued)

Pin No.	Mnemonic	Description
16	V _{DD2}	Supply Voltage for Isolator Side 2. This pin requires a 0.1 μ F bypass capacitor.

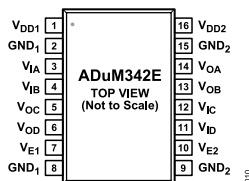
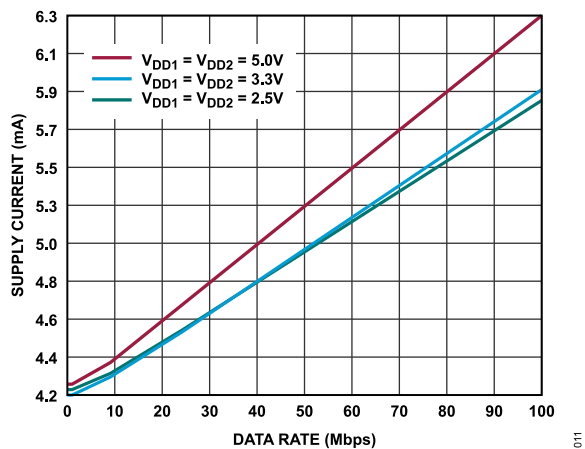
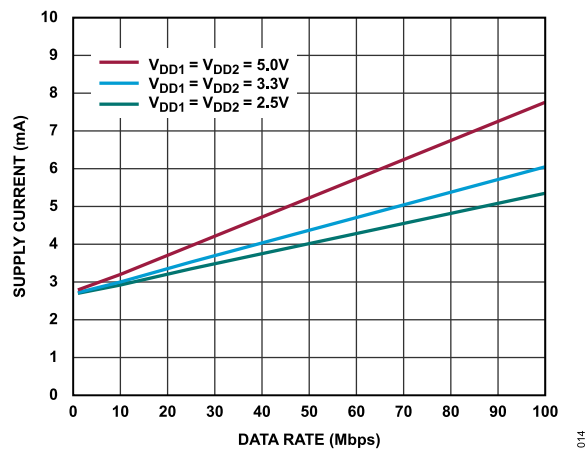
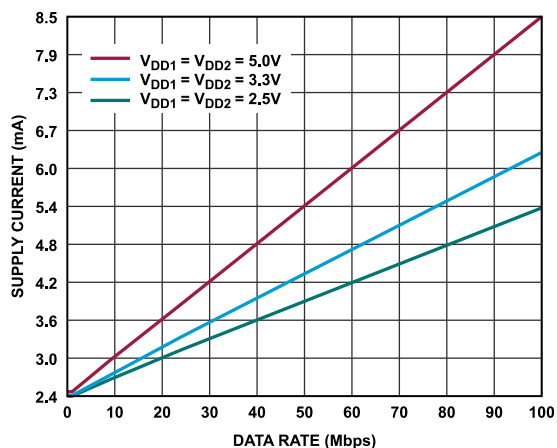
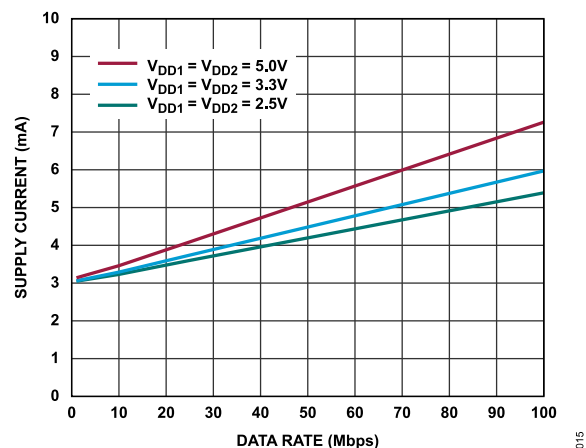
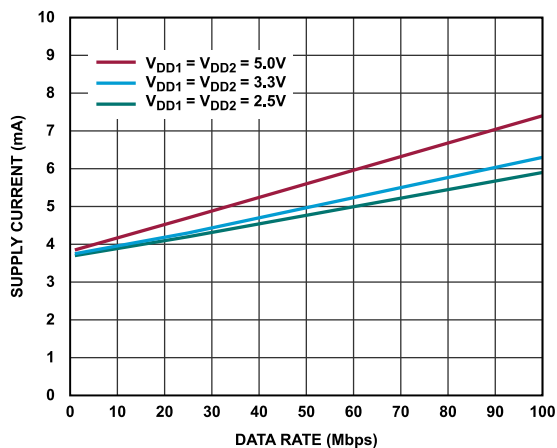
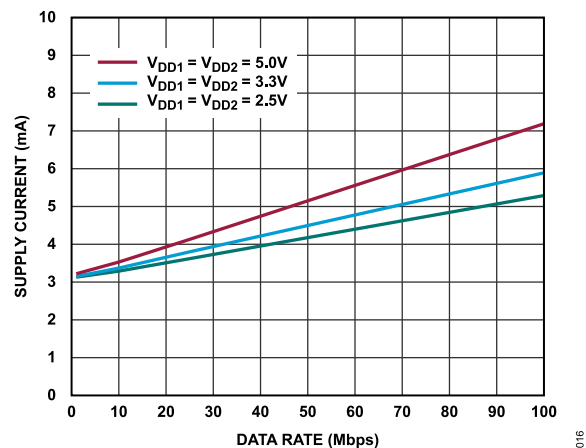


Figure 8. ADuM342E Pin Configuration

Table 17. ADuM342E Pin Function Descriptions

Pin No.	Mnemonic	Description
1	V _{DD1}	Supply Voltage for Isolator Side 1. This pin requires a 0.1 μ F bypass capacitor.
2, 8	GND ₁	Ground Reference for Isolator Side 1.
3	V _{IA}	Logic Input A.
4	V _{IB}	Logic Input B.
5	V _{OC}	Logic Output C.
6	V _{OD}	Logic Output D.
7	V _{E1}	Output Enable 1. Active high logic input. When V _{E1} is high or disconnected, the V _{OA} and V _{OB} output is enabled. When V _{E1} is low, the V _{OA} and V _{OB} output is disabled to the high-Z state.
9, 15	GND ₂	Ground Reference for Isolator Side 2.
10	V _{E2}	Output Enable 2. Active high logic input. When V _{E2} is high or disconnected, the V _{OC} and V _{OD} outputs are enabled. When V _{E2} is low, the V _{OC} and V _{OD} outputs are disabled to the high-Z state.
11	V _{ID}	Logic Input D.
12	V _{IC}	Logic Input C.
13	V _{OB}	Logic Output B.
14	V _{OA}	Logic Output A.
16	V _{DD2}	Supply Voltage for Isolator Side 2. This pin requires a 0.1 μ F bypass capacitor.

TYPICAL PERFORMANCE CHARACTERISTICS

Figure 9. ADuM340E I_{DD1} Supply Current vs. Data Rate at Various VoltagesFigure 12. ADuM341E I_{DD2} Supply Current vs. Data Rate at Various VoltagesFigure 10. ADuM340E I_{DD2} Supply Current vs. Data Rate at Various VoltagesFigure 13. ADuM342E I_{DD1} Supply Current vs. Data Rate at Various VoltagesFigure 11. ADuM341E I_{DD1} Supply Current vs. Data Rate at Various VoltagesFigure 14. ADuM342E I_{DD2} Supply Current vs. Data Rate at Various Voltages

TYPICAL PERFORMANCE CHARACTERISTICS

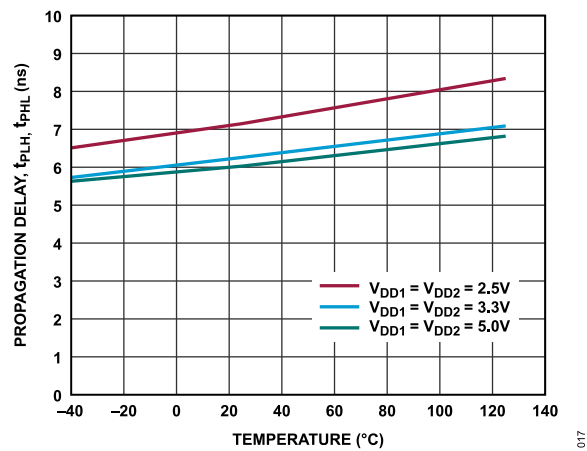


Figure 15. Propagation Delay, t_{PLH} , t_{PHL} vs. Temperature at Various Voltages

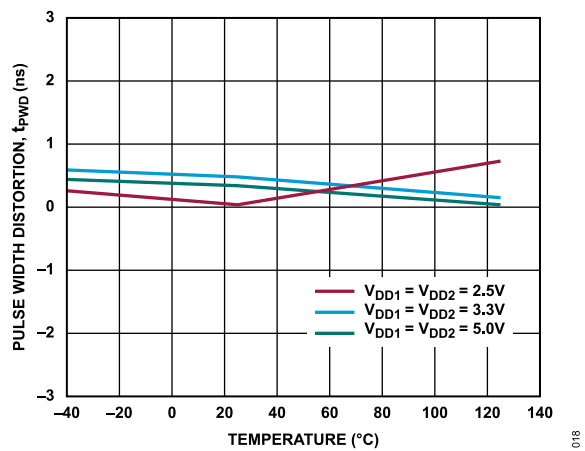


Figure 16. Pulse Width Distortion, t_{PWD} vs. Temperature at Various Voltages

THEORY OF OPERATION

The ADuM340E/ADuM341E/ADuM342E use a high frequency carrier to transmit data across the isolation barrier via iCoupler chip scale transformer coils separated by layers of polyimide isolation. Using an on/off keying (OOK) technique and the differential architecture shown in Figure 17 and Figure 18, the ADuM340E/ADuM341E/ADuM342E have very low propagation delay and high speed.

There is no interdependency between the V_{DD1} and V_{DD2} supplies. They can simultaneously operate at any voltage within their specified operating ranges and can sequence in any order. This feature enables the isolator to perform voltage translation of 2.5 V, 3.3 V, and 5 V logic. The architecture is designed for high common-mode transient (CMTI) immunity and high immunity to electrical noise and magnetic interference. Radiated emissions are minimized with a spread spectrum OOK carrier and other techniques.

Figure 17 illustrates the waveforms for models of the ADuM340E/ADuM341E/ADuM342E that have the condition of the fail-safe output state equal to low, where the carrier waveform is off when the input state is low. If the input side is off or not operating, the low fail-safe output state (ADuM340E0/ADuM341E0/ADuM342E0) sets the output to low. For the ADuM340E/ADuM341E/ADuM342E that have a high fail-safe output state, Figure 18 illustrates the conditions where the carrier waveform is off when the input state is high. When the input side is off or not operating, the high fail-safe output state (ADuM340E1/ADuM341E1/ADuM342E1) sets the output to high. See Figure 25 for the model numbers that have the fail-safe output state of low or the fail-safe output state of high.

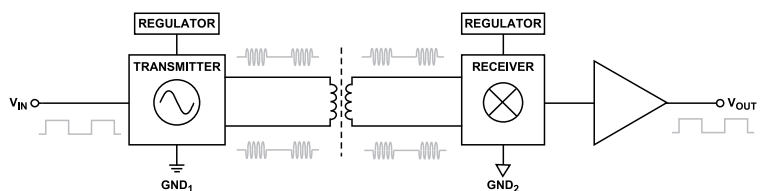


Figure 17. Operational Block Diagram of a Single Channel with a Low Fail-Safe Output State

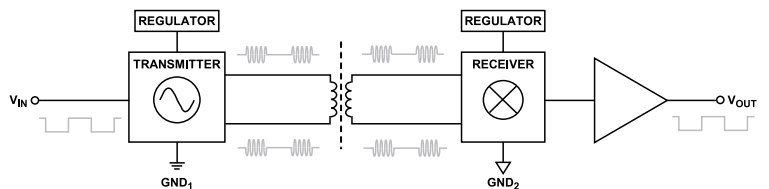


Figure 18. Operational Block Diagram of a Single Channel with a High Fail-Safe Output State

THEORY OF OPERATION

TRUTH TABLE

Table 18. ADuM340E/ADuM341E/ADuM342E Truth Table (Positive Logic)

V_{IX} Input ^{1,2}	V_{EX} Input ^{1,2}	V_{DDI} State ²	V_{DDO} State ²	Default Low (E0), V_{Ox} Output ^{1,2,3}	Default High (E1), V_{Ox} Output ^{1,2,3}	Test Conditions/ Comments
L	H or NC	Powered	Powered	L	L	Normal operation
H	H or NC	Powered	Powered	H	H	Normal operation
X	L	Powered	Powered	Z	Z	Outputs disabled
L	H or NC	Undervoltage	Powered	L	H	Fail-safe output
X^4	L^4	Undervoltage	Powered	Z	Z	Outputs disabled
X^4	X^4	Powered	Undervoltage	Indeterminate	Indeterminate	

¹ L means low, H means high, X means don't care, NC means not connected, and Z means high impedance within one diode drop of GND_x.
² V_{IX} and V_{Ox} refer to the input and output signals of a given channel (A, B, C, or D). V_{EX} refers to the output enable signal on the same side as the V_{Ox} outputs. V_{DDI} and V_{DDO} refer to the supply voltages on the input and output sides of the given channel, respectively.
³ E0 refers to ADuM340E0/ADuM341E0/ADuM342E0 models, and E1 refers to ADuM340E1/ADuM341E1/ADuM342E1 models. See the [Ordering Guide](#) section.
⁴ Input pins (V_{IX} , V_{EX}) on the same side as an unpowered supply must be in a low state to avoid powering the device through its ESD protection circuitry.

I/O Schematics

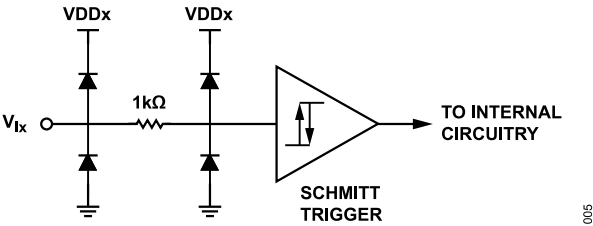


Figure 19. V_{IA} , V_{IB} , V_{IC} , V_{ID} Input Schematics

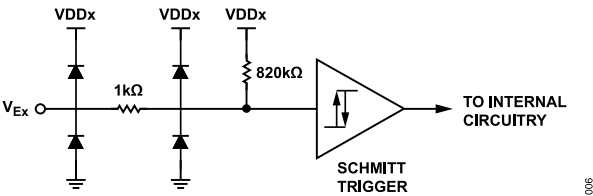


Figure 20. V_{E1} , V_{E2} Input Schematics

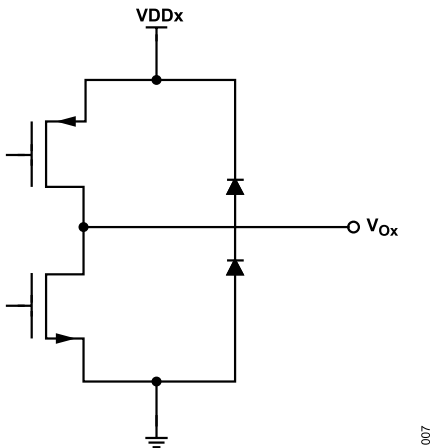


Figure 21. V_{OA} , V_{OB} , V_{OC} , V_{OD} Output Schematics

APPLICATIONS INFORMATION

PCB LAYOUT

The ADuM340E/ADuM341E/ADuM342E digital isolators require no external interface circuitry for the logic interfaces. Power supply bypassing is strongly recommended at the input and output supply pins (see Figure 22). Bypass capacitors are to be connected between Pin 1 and Pin 2 for V_{DD1} and between Pin 15 and Pin 16 for V_{DD2} . The required bypass capacitor value is between 0.01 μF and 0.1 μF . The total lead length between both ends of the capacitor and the input power supply pin must not exceed 10 mm. Low ESR capacitors are important for direct power injection (DPI) and CMTI performance. Bypassing between Pin 1 and Pin 8 and between Pin 9 and Pin 16 must also be considered, unless the ground pair on each package side is connected close to the package.

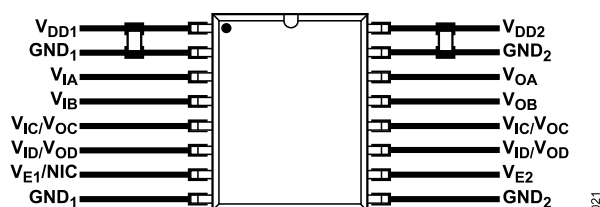


Figure 22. Recommended Printed Circuit Board Layout

In applications involving high common-mode transients, ensure that board coupling across the isolation barrier is minimized. Furthermore, design the board layout such that any coupling that does occur equally affects all pins on a given component side. Failure to ensure this design can cause voltage differentials between pins exceeding the absolute maximum ratings of the device, thereby leading to latch-up or permanent damage (see Table 12).

PROPAGATION DELAY RELATED PARAMETERS

Propagation delay is a parameter that describes the time required for a logic signal to propagate through a component. The propagation delay to a Logic 0 output may differ from the propagation delay to a Logic 1 output.

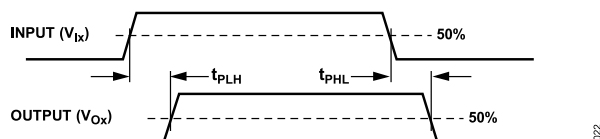


Figure 23. Propagation Delay Parameters

Pulse width distortion is the maximum difference between these two propagation delay values and is an indication of how accurately the timing of the input signal is preserved.

Channel matching is the maximum amount the propagation delay differs between channels within a single ADuM340E/ADuM341E/ADuM342E component.

Propagation delay skew is the maximum amount the propagation delay differs between multiple ADuM340E/ADuM341E/ADuM342E components operating under the same conditions.

JITTER MEASUREMENT

Figure 24 shows the resulting eye diagram for the ADuM341E. The measurement was taken using a Keysight 81160A pulse pattern generator at 100 Mbps with a pseudorandom bit sequence (PRBS15) input. Jitter was measured using the Tektronix 6 Series B mixed-signal oscilloscope, with a TAP1500 probe and using the Tektronix jitter and analysis software. The 10% to 90% rise and fall times of the input signal from the generator approximately equals 1.2 ns. The result shows a typical output eye diagram measured on the ADuM341E. Figure 24 shows random and deterministic jitter characteristics for a PRBS input.

Total jitter is evaluated at a BER of 1×10^{-12} and calculated for a PRBS input with and without the effects of crosstalk. The total jitter measurement without crosstalk consists of examining one channels input, while the adjacent channels inputs are grounded. The jitter measurement with crosstalk consists of all channels switching simultaneously at the same rate.

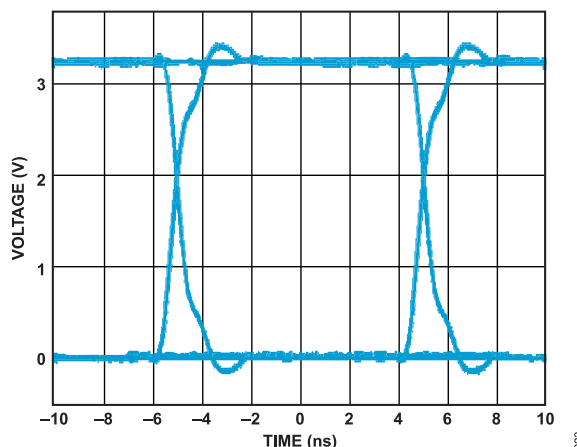


Figure 24. ADuM341E Output Channel Eye Diagram ($V_{DD1} = V_{DD2} = 3.3 \text{ V}$, 100 Mbps, $T_A = 25^\circ\text{C}$, $C_L = 15 \text{ pF}$, PRBS15 Input)

THERMAL ANALYSIS

The ADuM340E/ADuM341E/ADuM342E consist of two internal dies attached to a split lead frame with two die attach pads. For the purposes of thermal analysis, the dies are treated as a single thermal unit, with the highest junction temperature reflected in the thermal parameter values from Table 14. The thermal parameter values are based on thermal simulations with the devices mounted on a JEDEC standard, 4-layer board with fine width traces and still air. Under normal operating conditions, the ADuM340E/ADuM341E/ADuM342E can operate at full load across the full temperature range without derating the output current.

θ_{JA} and θ_{JB} are mainly used to compare the thermal performance of the package of the device with other semiconductor packages when all test conditions listed are similar. θ_{JA} and θ_{JB} can be used for first order approximation of the junction temperature in the system environment.

APPLICATIONS INFORMATION

If an accurate thermal measurement of the board temperature near the device under test or directly on the package top surface operating in the system environment is available along with the corresponding device power dissipation, then using Ψ_{JB} or Ψ_{JT} is a more appropriate way to estimate the junction temperature in the system environment. Use Ψ_{JB} when the temperature measurement point is on the board or Ψ_{JT} when it is on the package top. The junction temperature is estimated using the following equation:

$$T_J = \psi_{Jx} \times P_d + T_x \quad (1)$$

where

P_d is the dissipated power.

T_x is the measured temperature at location x and x is either B for the PCB or T for the package top.

The temperature measurement point for θ_{JB} and Ψ_{JB} is between Pin 12 and Pin 13 on the outer edge of the pin footprint. The temperature measurement point for Ψ_{JT} is at the center of the topside of the package.

INSULATION LIFETIME

All insulation structures eventually break down when subjected to voltage stress over a sufficiently long period. The rate of insulation degradation is dependent on the characteristics of the voltage waveform applied across the insulation as well as on the materials and material interfaces. Analog Devices conducts an extensive set of evaluations to determine the lifetime of the insulation structure within the ADuM340E/ADuM341E/ADuM342E as per IEC 60747-17.

OUTLINE DIMENSIONS

Package Drawing (Option)	Package Type	Package Description
RW-16	SOIC_W	16-Lead Standard Small Outline Package Wide Body
RQ-16	QSOP	16-Lead Shrink Small Outline Package

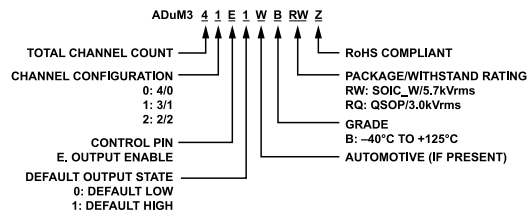


Figure 25. Product Selector Guide

ORDERING GUIDE

Model ^{1, 2}	Temperature Range	Package Description	Packing Quantity	Package Option
ADUM340E0BRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM340E0BRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM340E0BRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM340E0BRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM340E0WBRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM340E0WBRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM340E0WBRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM340E0WBRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM340E1BRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM340E1BRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM340E1BRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM340E1BRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM340E1WBRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM340E1WBRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM340E1WBRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM340E1WBRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM341E0BRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM341E0BRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM341E0BRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM341E0BRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM341E0WBRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM341E0WBRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM341E0WBRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM341E0WBRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM341E1BRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM341E1BRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM341E1BRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM341E1BRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM341E1WBRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM341E1WBRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM341E1WBRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM341E1WBRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM342E0BRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM342E0BRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16

OUTLINE DIMENSIONS

Model ^{1,2}	Temperature Range	Package Description	Packing Quantity	Package Option
ADUM342E0BRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM342E0BRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM342E0WBRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM342E0WBRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM342E0WBRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM342E0WBRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM342E1BRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM342E1BRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM342E1BRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM342E1BRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16
ADUM342E1WBRQZ	-40°C to +125°C	16-Lead QSOP		RQ-16
ADUM342E1WBRQZ-RL7	-40°C to +125°C	16-Lead QSOP	Reel, 1000	RQ-16
ADUM342E1WBRWZ	-40°C to +125°C	16-Lead SOIC Wide		RW-16
ADUM342E1WBRWZ-RL	-40°C to +125°C	16-Lead SOIC Wide	Reel, 1000	RW-16

¹ Z = RoHS Compliant Part.

² W = Qualified for Automotive Applications.

EVALUATION BOARDS

Model ¹	Description
EVAL-ADuM34XEEBZ	Evaluation Board for the ADuM340E, ADuM341E, and ADuM342E

¹ Z = RoHS Compliant Part.

AUTOMOTIVE PRODUCTS

The ADuM340E0W/ADuM340E1W/ADuM341E0W/ADuM341E1W/ADuM342E0W/ADuM342E1W models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the [Specifications](#) section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

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